	Type	L #	Hits	Search Text	DBs
1	BRS	L1	864	(laser (light adj emitting adj diode)) and @ad<"19990329" and fiducial	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
2	BRS	L2	971	(laser (light adj emitting adj diode)) and @ad<"19990329" and mesa and etch	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
3	BRS	L3	248	2 and fiber	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
4	BRS	L4	0	2 and (locating adj surface)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
5	BRS	L5	136	(laser (light adj emitting adj diode)) and @ad<"19990329" and (locating adj surface)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB

	Time Stamp
6	2004/11/09 13:00
7	2004/11/09 13:08
8	2004/11/09 13:21
9	2004/11/09 13:21

	Type	L #	Hits	Search Text	DBs
6	BRS	L6	1	(laser (light adj emitting adj diode)) and @ad<"19990329" and (silicon adj workbench)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
7	BRS	L7	103262	(laser (light adj emitting adj diode)) and @ad<"19990329" and (alignment location spacing)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
8	BRS	L8	500	(laser (light adj emitting adj diode)) and @ad<"19990329" and (alignment location spacing) and etch and mesa	US-PGPUB; USPAT; EPO; JPO; IBM_TDB
9	BRS	L9	937	(laser (light adj emitting adj diode)) and @ad<"19990329" and silicon and (flip adj chip)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB

	Time Stamp
1	2004/11/09 12:42
2	2004/11/09 12:57
3	2004/11/09 12:56
4	2004/11/09 12:56
5	2004/11/09 13:07